



# P-Channel 1.8-V (G-S) MOSFET

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}(\Omega)$	I <sub>D</sub> (A)		
	$0.045$ at $V_{GS} = -4.5 \text{ V}$	- 3.5		
- 8	0.072 at V <sub>GS</sub> = - 2.5 V	- 2.8		
	0.120 at V <sub>GS</sub> = - 1.8 V	- 2.0		

## **FEATURES**

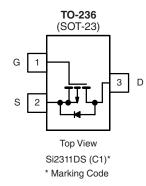
- Halogen-free Option Available
- TrenchFET® Power MOSFET



#### RoHS COMPLIANT

## **APPLICATIONS**

· Load Switch



Ordering Information: Si2311DS-T1-E3 (Lead (Pb)-free)

Si2311DS-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS	T <sub>A</sub> = 25 °C, unle	ss otherwise i	noted		
Parameter		Symbol	5 s	Steady State	Unit
Drain-Source Voltage		V <sub>DS</sub>	- 8		V
Gate-Source Voltage		$V_{GS}$	± 8		V
Ocaliana Daria Ocana (T. 450 00)3 h	T <sub>A</sub> = 25 °C	I <sub>D</sub>	- 3.5	- 3.0	
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a, b</sup>	T <sub>A</sub> = 70 °C		- 2.8	- 2.4	٨
Pulsed Drain Current		I <sub>DM</sub>	- 10		Α
Continuous Source Current (Diode Conduction) <sup>a, b</sup>		I <sub>S</sub>	- 0.8	- 0.6	
	T <sub>A</sub> = 25 °C	P <sub>D</sub>	0.96	0.71	W
Maximum Power Dissipation <sup>a, b</sup>	T <sub>A</sub> = 70 °C		0.62	0.46	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Manifestor Localitan to Applicant	t ≤ 5 s	- R <sub>thJA</sub>	100	130	°C/W
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		140	175	
Maximum Junction-to-Foot (Drain)	Steady State	R <sub>thJF</sub>	60	75	

#### Notes:

- a. Surface Mounted on FR4 board.
- b. Pulse width limited by maximum junction temperature.

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<b>SPECIFICATIONS</b> T <sub>J</sub> = 25 °C, unless otherwise noted							
			Limits				
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0 \text{ V}, I_D = -10 \mu\text{A}$	- 8			V	
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = -250 \mu A$	- 0.45		- 0.8		
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V$ , $V_{GS} = \pm 8 V$			± 100	nA	
Zoro Coto Voltago Drain Current		$V_{DS} = -6.4 \text{ V}, V_{GS} = 0 \text{ V}$			- 1	μΑ	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = - 6.4 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 55 °C			- 10		
	1	$V_{DS} \le -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	- 6			- A	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \le -5 \text{ V}, V_{GS} = -2.5 \text{ V}$	- 3				
		V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 3.5 A		0.036	0.045		
Drain-Source On-Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = -2.5 \text{ V}, I_D = -3 \text{ A}$		0.058	0.072	Ω	
		V <sub>GS</sub> = - 1.8 V, I <sub>D</sub> = - 0.7 A		0.096	0.120		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = -5 \text{ V}, I_{D} = -3.5 \text{ A}$		9.0		S	
Diode Forward Voltage	$V_{SD}$	$I_S = -0.8 \text{ A}, V_{GS} = 0 \text{ V}$			- 1.2	٧	
Dynamic <sup>b</sup>							
Total Gate Charge	$Q_g$	V - 4VV - 45V		8.5	12		
Gate-Source Charge	$Q_{gs}$	$V_{DS} = -4 \text{ V}, V_{GS} = -4.5 \text{ V}$ $I_{D} \cong -3.5 \text{ A}$		1.5		nC	
Gate-Drain Charge	$Q_{gd}$	. <sub>D</sub> _ 0.0 / t		2.1			
Input Capacitance	C <sub>iss</sub>			970			
Output Capacitance	C <sub>oss</sub>	$V_{DS} = -4 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		485		pF	
Reverse Transfer Capacitance	C <sub>rss</sub>			160		1	
Switching <sup>b</sup>							
Turn-On Time	t <sub>d(on)</sub>	V 4V D 4 C		18	25		
Tutti-Ott Tillie	t <sub>r</sub>	$V_{DD} = -4 \text{ V}, R_L = 4 \Omega$ $I_D \cong -1.0 \text{ A}, V_{GEN} = -4.5 \text{ V}$		45	65	no	
Turn-Off Time	t <sub>d(off)</sub>			40	60	ns	
Turri-Oir Time	t <sub>f</sub>	$R_G = 6 \Omega$		45	65		

#### Notes:

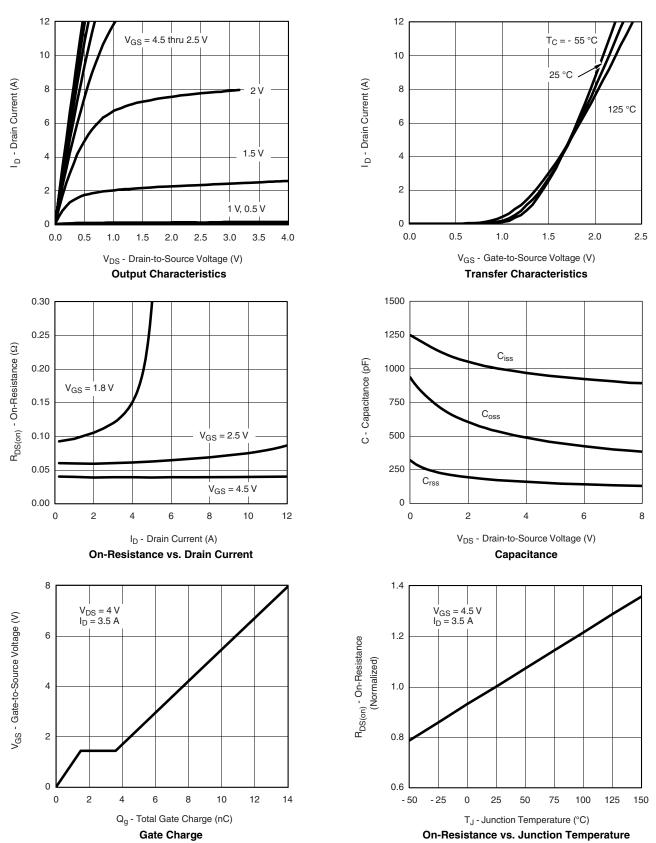
- a. For DESIGN AID ONLY, not subject to production testing.
- b. Pulse test: PW  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.
- c. Switching time is essentially independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.





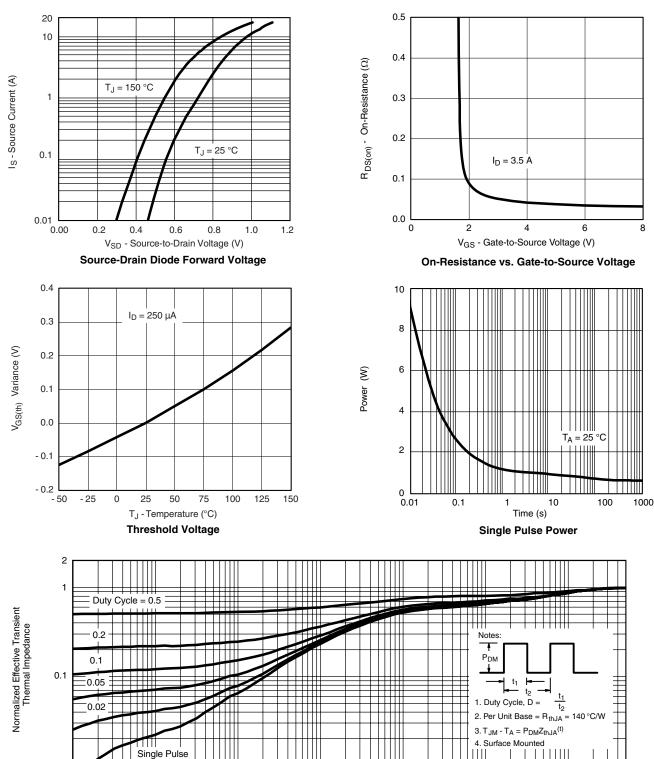
## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



#### Normalized Thermal Transient Impedance, Junction-to-Ambient

Square Wave Pulse Duration (s)

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0.01

10-4

10<sup>-3</sup>

10-2

100

10

500



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